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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR μ PA1742TP

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The μ PA1742TP is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

FEATURES

- High voltage: VDSS = 250 V
- Gate voltage rating: ±30 V
- Low on-state resistance

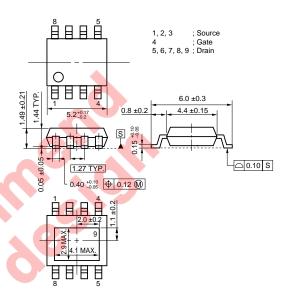
RDS(on) = 0.55Ω MAX. (VGS = 10 V, ID = 3.5 A)

- Low input capacitance
 - Ciss = 460 pF TYP. (VDS = 10 V, VGS = 0 V)
- · Built-in gate protection diode
- Small and surface mount package (Power HSOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1742TP	Power HSOP8

PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise noted. All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	VDSS	250	V	
Gate to Source Voltage (Vps = 0 V)	Vgss	±30	V	
Drain Current (DC) (Tc = 25°C)	ID(DC)	±7.0	Α	
Drain Current (pulse) Note1	D(pulse)	±21	Α	
Total Power Dissipation (Tc = 25°C)	P _{T1}	24	W	
Total Power Dissipation (T _A = 25°C) Note2	P _{T2}	1.0	W	
Channel Temperature	T_ch	150	°C	
Storage Temperature	T_{stg}	-55 to +150	°C	
Single Avalanche Current Note3	IAS	7.0	Α	
Single Avalanche Energy Note3	Eas	4.9	mJ	
Repetitive Avalanche Current Note4	Iar	7.0	Α	
Repetitive Pulse Avalanche Energy Note4	Ear	4.9	mJ	

Gate Body Diode

Source

Protection

Diode

EQUIVALENT CIRCUIT

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm
- 3. Starting T_{ch} = 25°C, V_{DD} = 125 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = 20 \rightarrow 0 V
- **4.** $T_{ch(peak)} \le 150^{\circ}C$, L = 100 μH

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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ELECTRICAL CHARACTERISTICS (TA = 25°C, unless otherwise noted. All terminals are connected.)

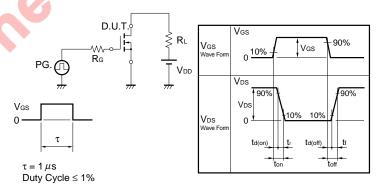
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 250 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±30 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5	3.5	4.5	V
Forward Transfer Admittance Note	yfs	V _{DS} = 10 V, I _D = 3.5 A	2.5	5		S
Drain to Source On-state Resistance Note	RDS(on)	Vgs = 10 V, ID = 3.5 A		0.41	0.55	Ω
Input Capacitance	Ciss	V _{DS} = 10 V		460		pF
Output Capacitance	Coss	Vgs = 0 V		100		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		45		pF
Turn-on Delay Time	td(on)	V _{DD} = 125 V, I _D = 3.5 A		11		ns
Rise Time	tr	Vgs = 10 V		9		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$	>	24		ns
Fall Time	t _f			8		ns
Total Gate Charge	Q _G	V _{DD} = 200 V		14		nC
Gate to Source Charge	Qgs	Vgs = 10 V		3		nC
Gate to Drain Charge	Q _{GD}	lo = 7.0 A		7		nC
Body Diode Forward Voltage Note	V _F (S-D)	IF = 7.0 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 7.0 A, VGS = 0 V		140		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		560		nC

Note Pulsed: PW \leq 800 μ s, Duty Cycle \leq 2%

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD}

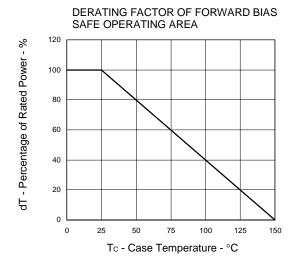
TEST CIRCUIT 2 SWITCHING TIME

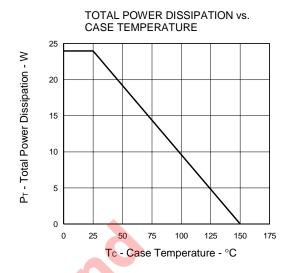


TEST CIRCUIT 3 GATE CHARGE

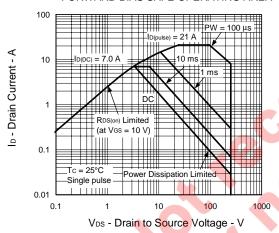
$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \\ PG. \\ \hline \end{array} \begin{array}{c} S \\ \hline \\ \end{array} \begin{array}{c} D.U.T. \\ \hline \\ \end{array} \begin{array}{c} \\ \\ \hline \\ \end{array} \begin{array}{c} \\ \\$$

TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise noted. All terminals are connected.)



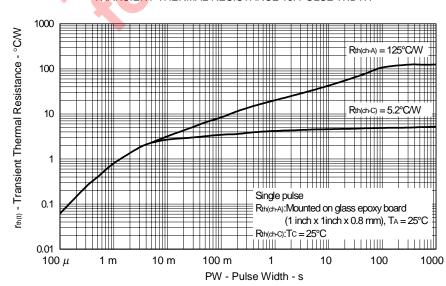


FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

Maesil

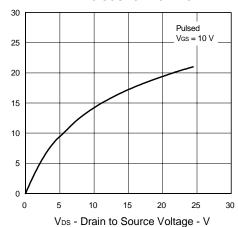


Data Sheet G16325EJ1V0DS 3

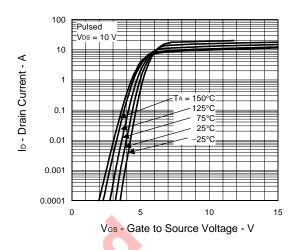
Ip - Drain Current - A

Ves(off) - Gate Cut-off Voltage - V

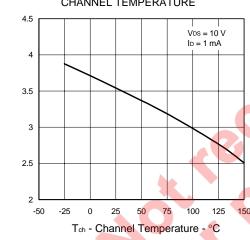
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



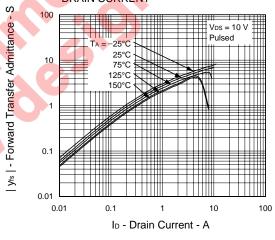
FORWARD TRANSFER CHARACTERISTICS



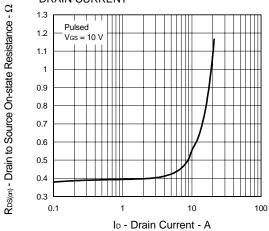
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



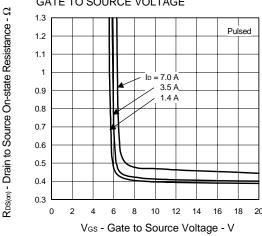
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



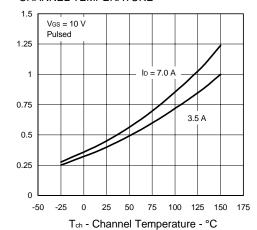
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



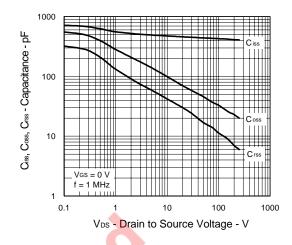
 $\mathsf{Res}_{(m)}$ - Drain to Source On-state Resistance - Ω

IF - Diode Forward Current - A

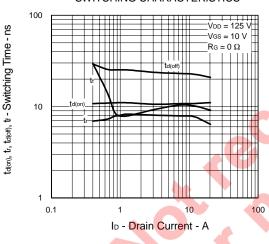
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



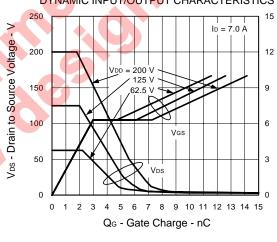
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



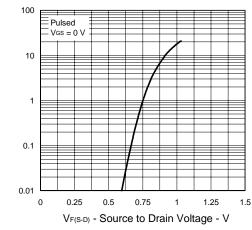
SWITCHING CHARACTERISTICS



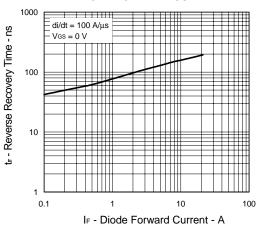
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



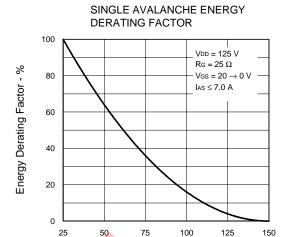
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD 10 Void 125 V Ref = 25 Ω Void = 20 \to 0 V Eas = 4.9 mJ 0.1 0.001 0.01 0.1 1 10 L - Inductive Load - mH



Starting Tch - Starting Channel Temperature - °C

NEC μ PA1742TP

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